



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## SCH1333 — P-Channel Silicon MOSFET General-Purpose Switching Device Applications

### Features

- 1.8V drive
- Halogen free compliance
- Protection diode in

### Specifications

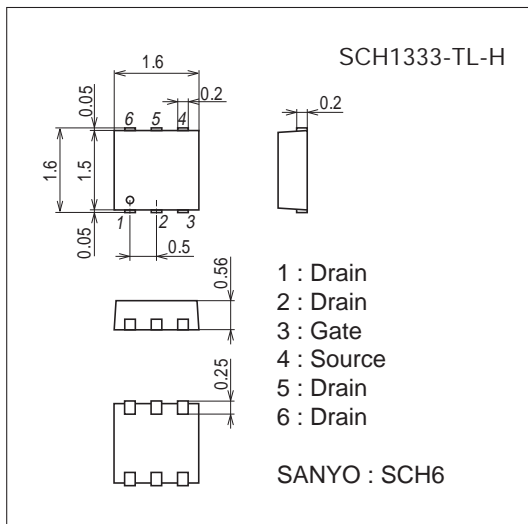
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-2	A
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-8	A
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Package Dimensions

unit : mm (typ)

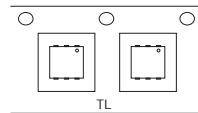
7028-002



### Product & Package Information

- Package : SCH6
- JEITA, JEDEC : SOT-563
- Minimum Packing Quantity : 5,000 pcs./reel

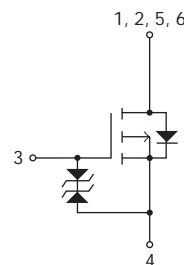
Packing Type : TL



Marking



### Electrical Connection

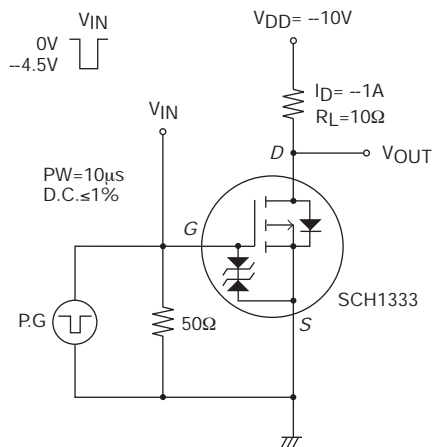


# SCH1333

## Electrical Characteristics at Ta=25°C

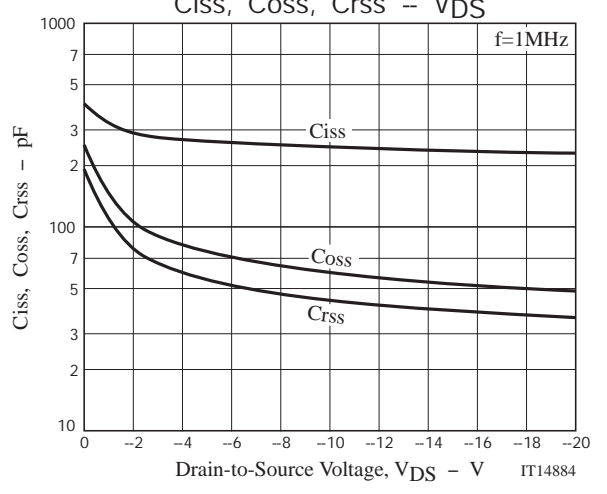
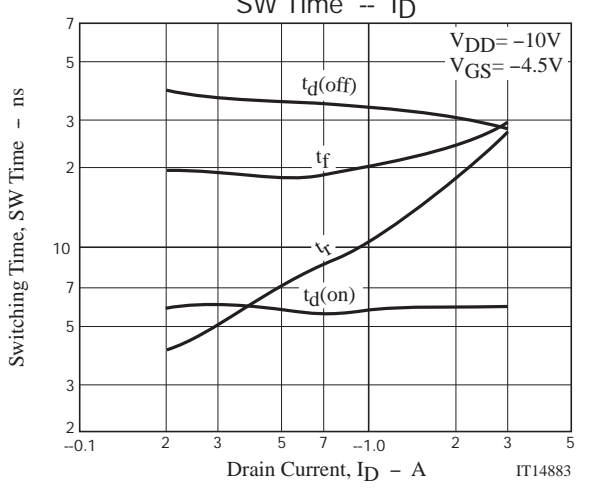
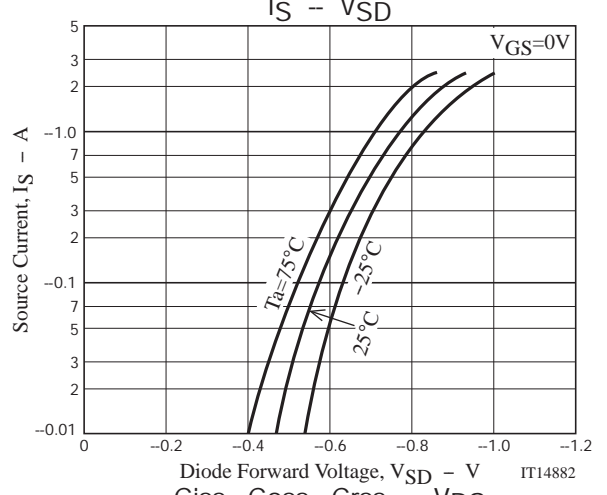
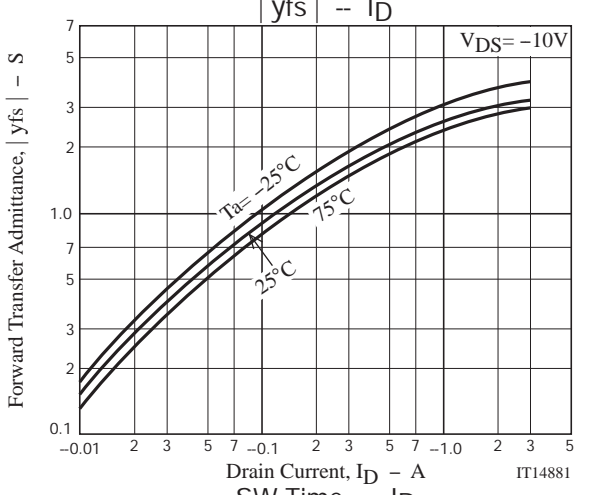
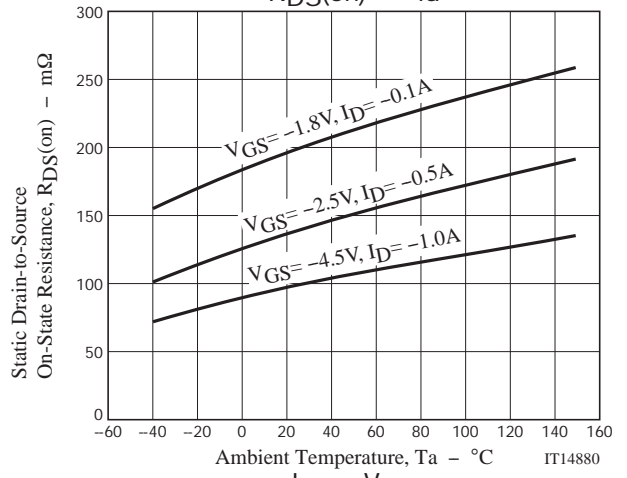
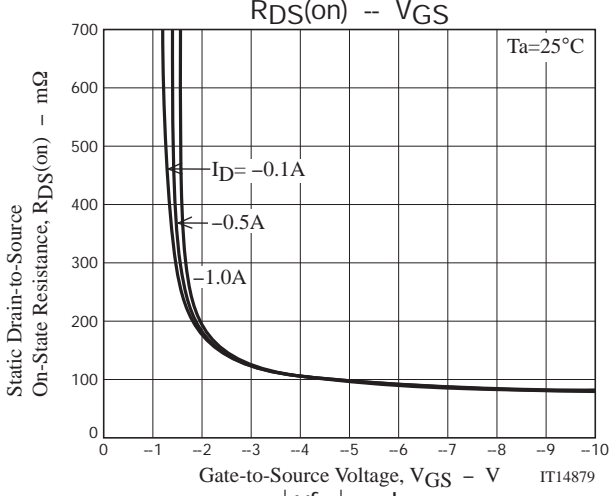
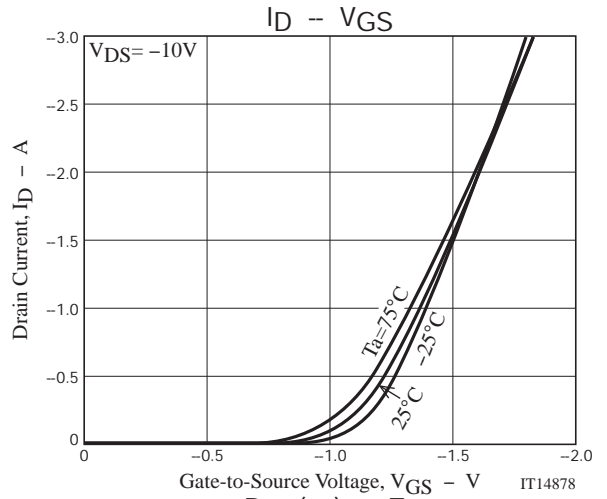
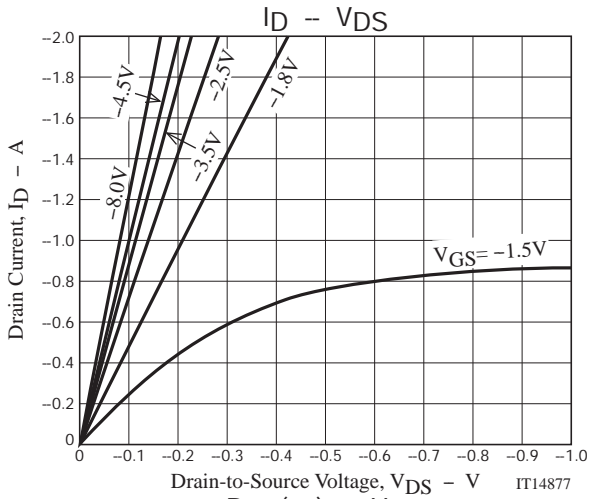
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =-1mA, V <sub>GS</sub> =0V	-20			V
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V			-1	μA
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μA
Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA	-0.4		-1.4	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-1A		2.7		S
Static Drain-to-Source On-State Resistance	R <sub>DS(on)1</sub>	I <sub>D</sub> =-1A, V <sub>GS</sub> =-4.5V		100	130	mΩ
	R <sub>DS(on)2</sub>	I <sub>D</sub> =-0.5A, V <sub>GS</sub> =-2.5V		140	196	mΩ
	R <sub>DS(on)3</sub>	I <sub>D</sub> =-0.1A, V <sub>GS</sub> =-1.8V		210	315	mΩ
Input Capacitance	C <sub>iss</sub>			250		pF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =-10V, f=1MHz		60		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			45		pF
Turn-ON Delay Time	t <sub>d(on)</sub>	See specified Test Circuit.		5.7		ns
Rise Time	t <sub>r</sub>			11		ns
Turn-OFF Delay Time	t <sub>d(off)</sub>			34		ns
Fall Time	t <sub>f</sub>			20		ns
Total Gate Charge	Q <sub>g</sub>				3.3	
Gate-to-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-10V, V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2A		0.65		nC
Gate-to-Drain "Miller" Charge	Q <sub>gd</sub>			0.72		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-2A, V <sub>GS</sub> =0V		-0.85	-1.2	V

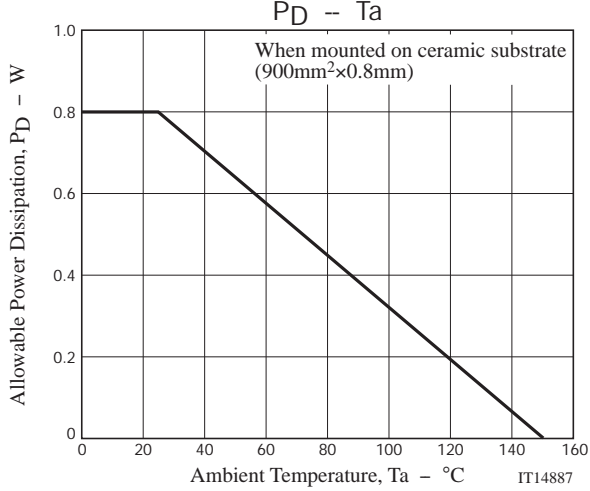
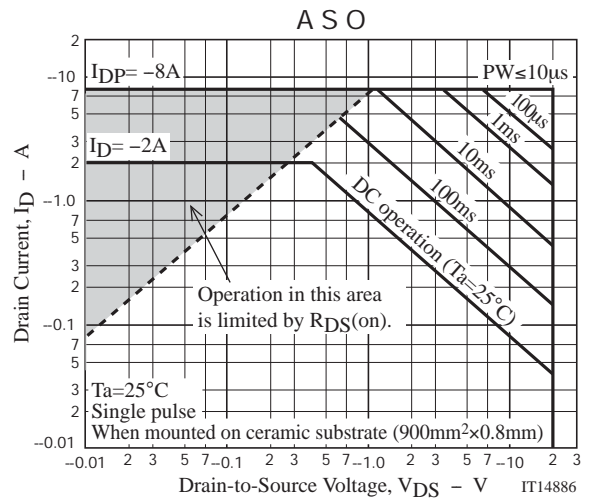
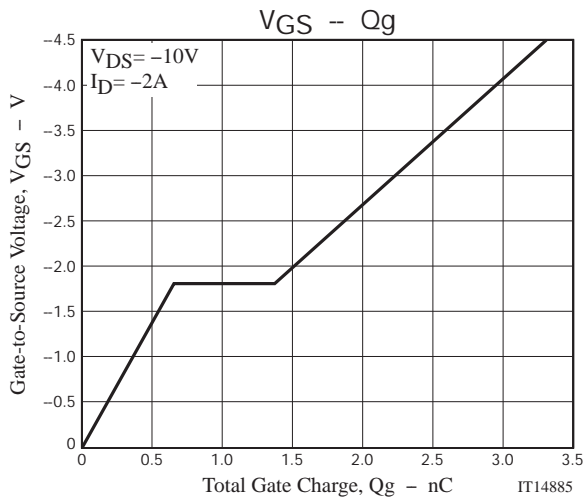
## Switching Time Test Circuit



## Ordering Information

Device	Package	Shipping	memo
SCH1333-TL-H	SCH6	5,000pcs./reel	Pb Free and Halogen Free





Taping Specification

SCH1333-TL-H

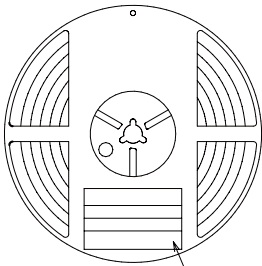
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
SCH6	SCH6	5,000	25,000	150,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit:mm)

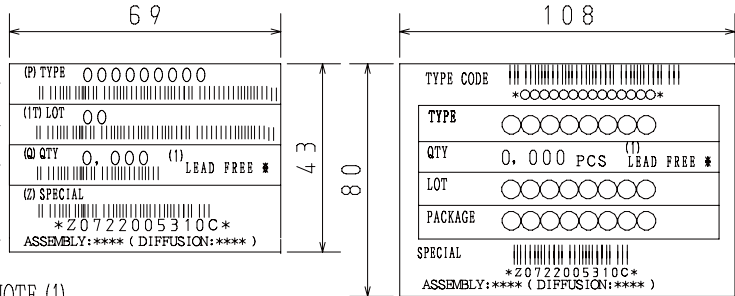
Outer box label  
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

Packing method



Type No.  
LOT No.  
Quantity  
Origin

Reel label



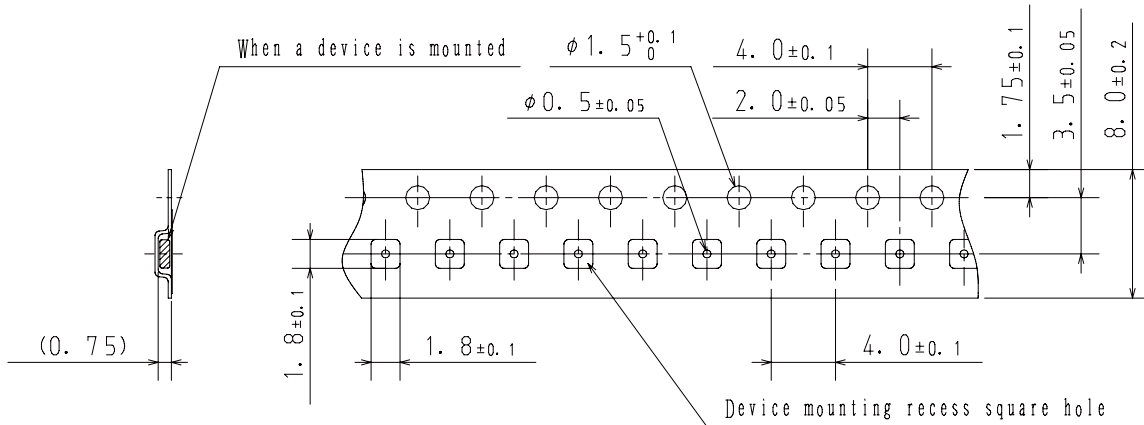
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

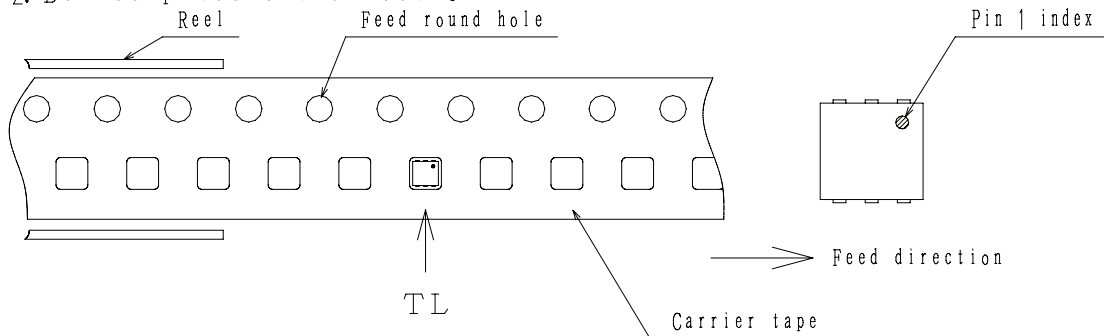
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



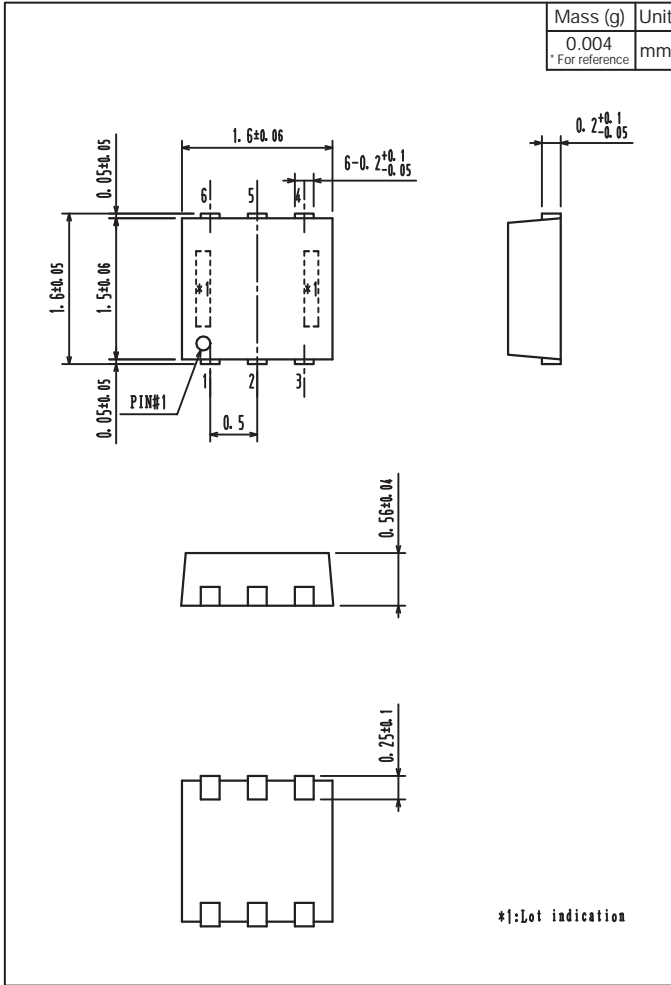
2-2. Device placement direction



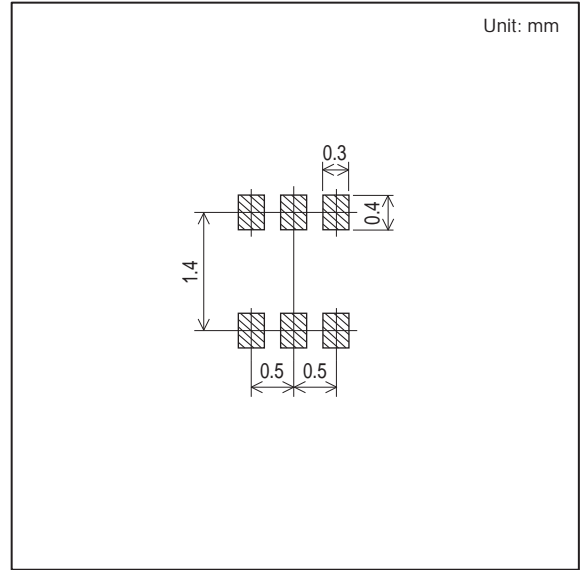
Those with pin 1 index on the feed hole side.....TL

# SCH1333

## Outline Drawing SCH1333-TL-H



## Land Pattern Example



Note on usage : Since the SCH1333 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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